

CORRECTION

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## Correction: Raman spectroscopy study of K-birnessite single crystals

Dong Han Ha,<sup>\*a</sup> Gichang Noh,<sup>bc</sup> Hakseong Kim,<sup>d</sup> Dong Hwan Kim,<sup>a</sup> Jeongho Kim,<sup>b</sup> Suyong Jung,<sup>a</sup> Chanyong Hwang,<sup>d</sup> Ha Young Lee,<sup>e</sup> Yong Ju Yun,<sup>f</sup> Joon Young Kwak,<sup>g</sup> Kibum Kang<sup>b</sup> and Sam Nyung Yi<sup>\*e</sup>

Correction for 'Raman spectroscopy study of K-birnessite single crystals' by Dong Han Ha *et al.*, *J. Mater. Chem. A*, 2025, **13**, 617–626, <https://doi.org/10.1039/D4TA06118G>.

The authors regret that throughout the published article, the term 'interlayer phonon mode' was incorrectly referred to as 'acoustic phonon mode'. Readers are advised of seven instances of this incorrect term in the following locations:

- (1) In the Abstract, in the sentence beginning "An acoustic phonon mode of birnessite is identified ..."
- (2) In the Introduction, in the sentences beginning "By measuring the Raman spectra of impurity-free K-birnessite ..." and "The interlayer spacing exerts a significant influence ..."
- (3) In the Results and discussion, subsection 'Temperature effect', in the sentences beginning "The  $\alpha$  peak exhibits typical characteristics ..." and "The acoustic phonon mode is indicative ..."
- (4) In the Conclusions, in the sentence beginning "An acoustic phonon mode ( $\alpha$  peak) of birnessite ..."

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.



<sup>a</sup>Division of Chemical and Material Metrology, Korea Research Institute of Standards and Science, Daejeon 34113, South Korea. E-mail: [dhha@kribs.re.kr](mailto:dhha@kribs.re.kr)

<sup>b</sup>Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Daejeon 34141, South Korea

<sup>c</sup>Center for Neuromorphic Engineering, Korea Institute of Science and Technology, Seoul 02792, South Korea

<sup>d</sup>Quantum Technology Institute, Korea Research Institute of Standards and Science, Daejeon 34113, South Korea

<sup>e</sup>Department of Nano-Semiconductor Engineering, Korea Maritime & Ocean University, Busan 49112, South Korea. E-mail: [snyi@kmou.ac.kr](mailto:snyi@kmou.ac.kr)

<sup>f</sup>Department of Integrative Energy Engineering, Graduate School of Energy and Environment (KU-KIST Green School), College of Engineering, Korea University, Seoul 02841, South Korea

<sup>g</sup>Division of Electronic and Semiconductor Engineering, Ewha Womans University, Seoul 03760, South Korea